

iscN-Channel MOSFET Transistor

TK8A50DA

• FEATURES

- Low drain-source on-resistance: RDS(ON) = 1.04Ω (MAX)
- Enhancement mode:
 - Vth = 2.4 to 4.4V (VDs = 10 V, ID=1.0mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

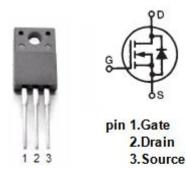
DESCRITION

ABSO

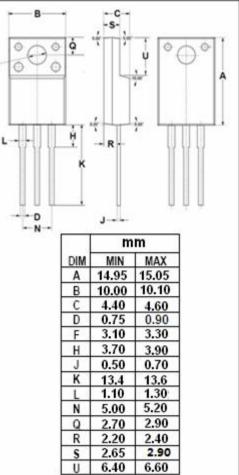
	ABSOLUTE MAXIMUM RATINGS(T _a =25°C)						
YMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Drain-Source Voltage	500	V				
V_{GS}	Gate-Source Voltage	±30	V				
ID	Drain Current-Continuous	7.5	A				
I _{DM}	Drain Current-Single Pulsed	30	А				
P _D	Total Dissipation @T _C =25℃	35	w				
Tj	Max. Operating Junction Temperature	150	°C				
T _{stg}	Storage Temperature	-55~150	°C				

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SYMBOL MAX PARAMETER UNIT °C/W Rth(ch-c) Channel-to-case thermal resistance 3.57



TO-220F package



isc website: www.iscsemi.cn

isc & iscsemi is registered trademark



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	500			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = 10V; I _D =1.0mA	2.4		4.4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =3.8A			1.04	Ω
lgss	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} = 0V			±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =500V; V _{GS} = 0V			10	μA
V _{SDF}	Diode forward voltage	I _{DR} =7.5A, V _{GS} = 0 V			1.7	V



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